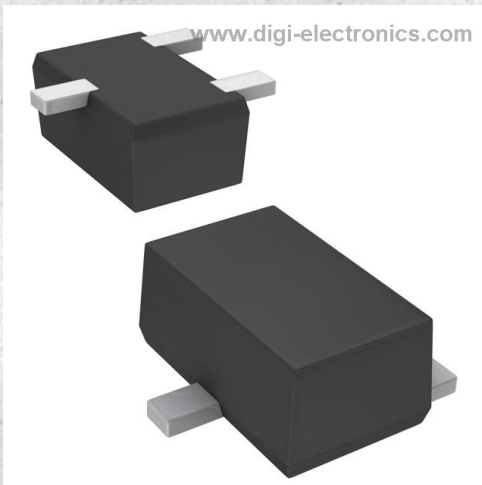


2SD18200RL Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	2SD18200RL-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SD18200RL
Description	TRANS NPN 25V 0.5A SMINI3
Detailed Description	Bipolar (BJT) Transistor NPN 25 V 500 mA 200MHz 1 50 mW Surface Mount SMini3-G1



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

2SD18200RL

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

25 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

150 mW

Operating Temperature:

150°C (TJ)

Package / Case:

SC-70, SOT-323

Base Product Number:

2SD1820

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

500 mA

Vce Saturation (Max) @ Ib, Ic:

600mV @ 30mA, 300mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

120 @ 150mA, 10V

Frequency - Transition:

200MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SMini3-G1

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0075

ECCN:

EAR99

2SD1820

Silicon NPN epitaxial planar type

For general amplification
Complementary to 2SB1219

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	30	V
Collector-emitter voltage (Base open)	V_{CEO}	25	V
Emitter-base voltage (Collector open)	V_{EBO}	5	V
Collector current	I_C	500	mA
Peak collector current	I_{CP}	1	A
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

■ Package

- Code
SMini3-G1
- Pin Name
 1. Base
 2. Emitter
 3. Collector

■ Marking Symbol: W

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	30			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	25			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μA
Forward current transfer ratio *1	h_{FE1} *2	$V_{CE} = 10 \text{ V}, I_C = 150 \text{ mA}$	85		340	—
	h_{FE2}	$V_{CE} = 10 \text{ V}, I_C = 500 \text{ mA}$	40			
Collector-emitter saturation voltage *1	$V_{CE(sat)}$	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		0.35	0.60	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6	15	pF

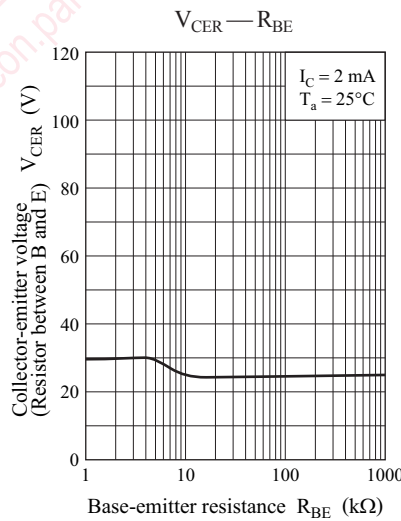
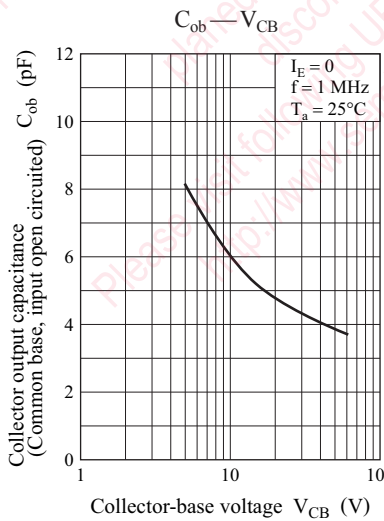
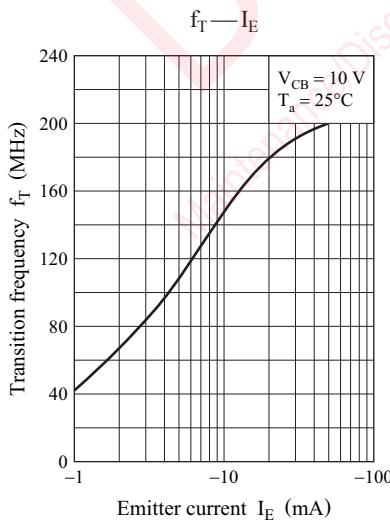
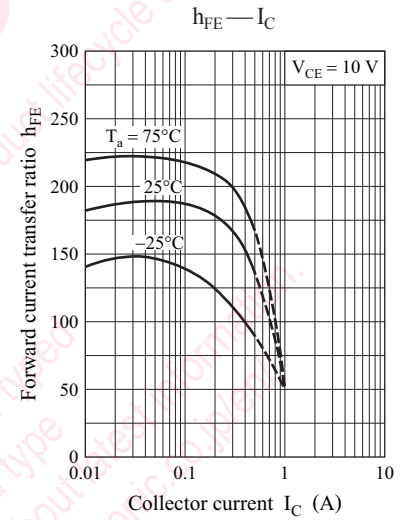
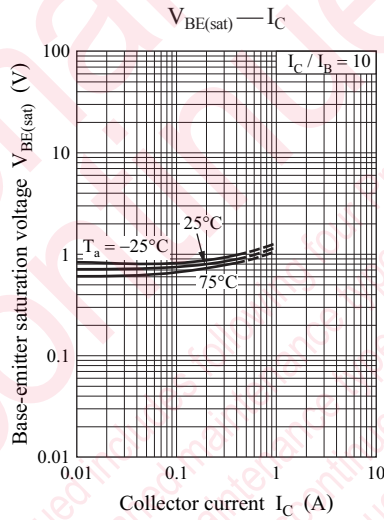
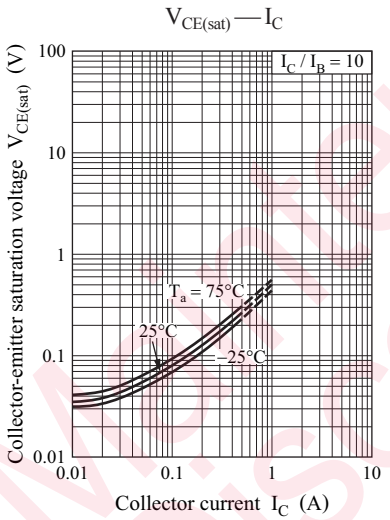
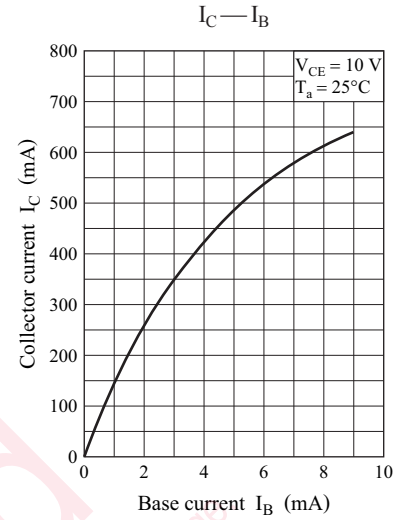
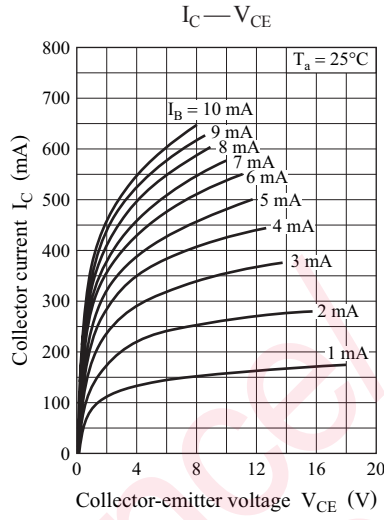
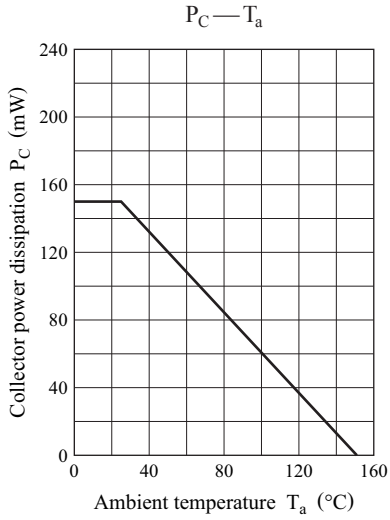
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

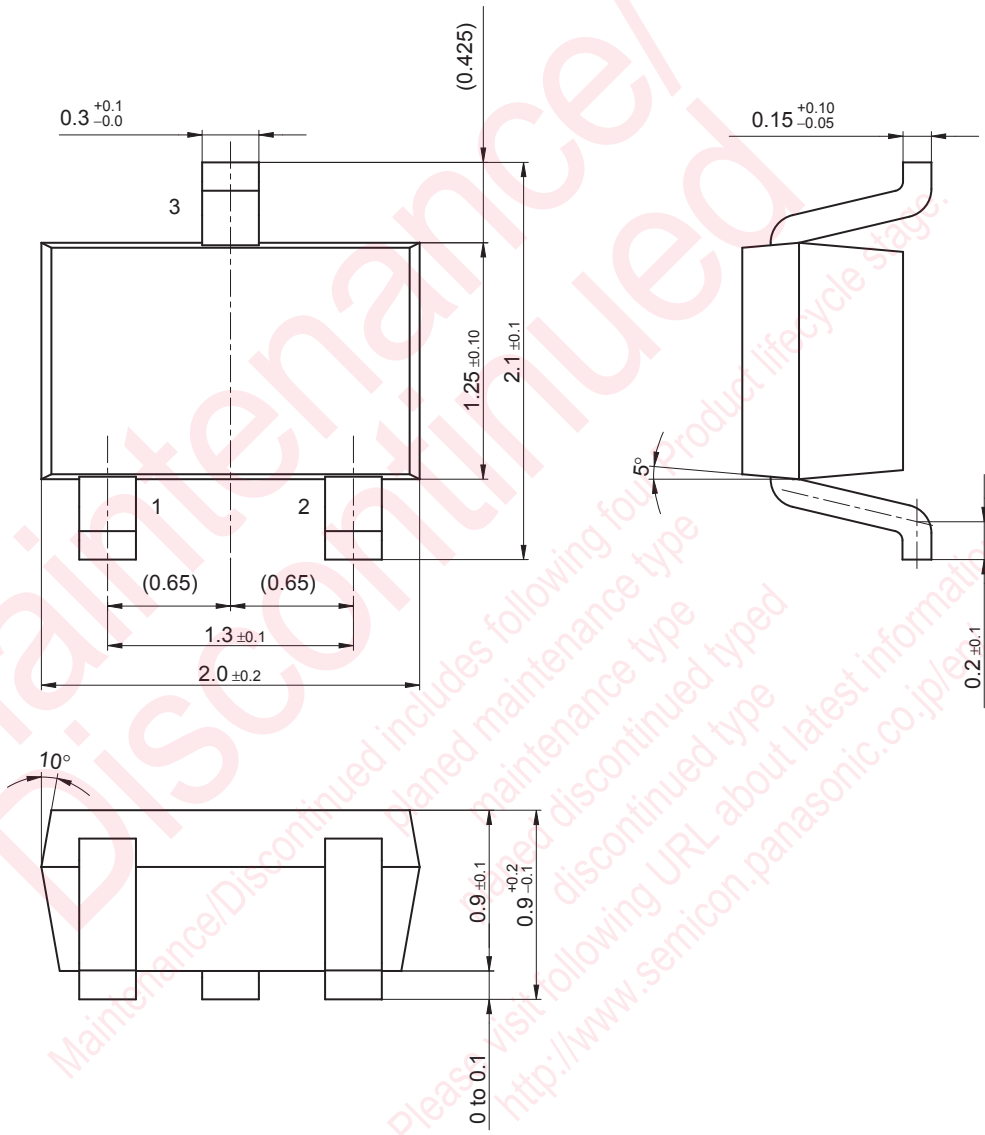
Rank	Q	R	S	No-rank
h_{FE1}	85 to 170	120 to 240	170 to 340	85 to 340
Marking symbol	WQ	WR	WS	—

Product of no-rank is not classified and have no marking symbol for rank.



SMini3-G1

Unit: mm



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